



# QL12x16 pASIC 1 FAMILY Very-High-Speed 2K (6K) Gate CMOS FPGA

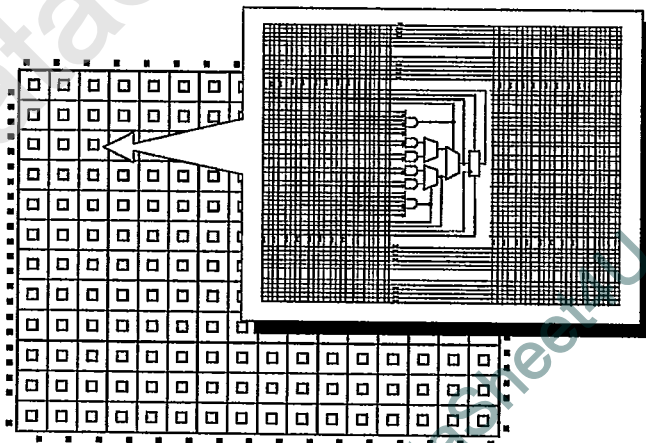
## pASIC HIGHLIGHTS

**...6000 total  
available gates**

## QL12x16 Block Diagram

**192 logic cells**

- ✕ **Very High Speed** – ViaLink™ metal-to-metal programmable-via anti-fuse technology, allows counter speeds over 100 MHz, and logic cell delays of under 4 ns.
- ✕ **High Usable Density** – A 12-by-16 array of 192 logic cells provides 6000 total available, with 2000 typically usable “gate array” gates in 84- and 68-pin PLCC packages, and a 100-pin Thin PQFP package.
- ✕ **Low-Power, High-Output Drive** – Stand-by current typically 2 mA. A 16-bit counter operating at 100 MHz consumes 50 mA. Minimum IOL and IOH of 8 mA.
- ✕ **Flexible FPGA Architecture** – The pASIC™ logic cell supports efficient, high-speed arithmetic, counter, data path, state machine and random logic applications with up to 14-input gates.
- ✕ **Low-Cost, Easy-to-Use Design Tools** – Designs entered and simulated using third-party, CAE tools. Fast, fully automatic place and route on PC and workstation platforms.



■ = Up to 68 I/O cells, 6 Input high-drive cells, 2 Input/CLK (high-drive) cells.





## PRODUCT SUMMARY

The QL12x16 is a member of the pASIC 1 Family of very-high-speed CMOS user-programmable ASIC (pASIC) devices. The 192 logic cell field-programmable gate array (FPGA) offers up to 6000 total available, with 2000 typically usable "gate array" gates (equivalent to 6000 gate claims of EPLD or LCA vendors) of high-performance general-purpose logic in 68- and 84-pin plastic leaded chip carrier packages.

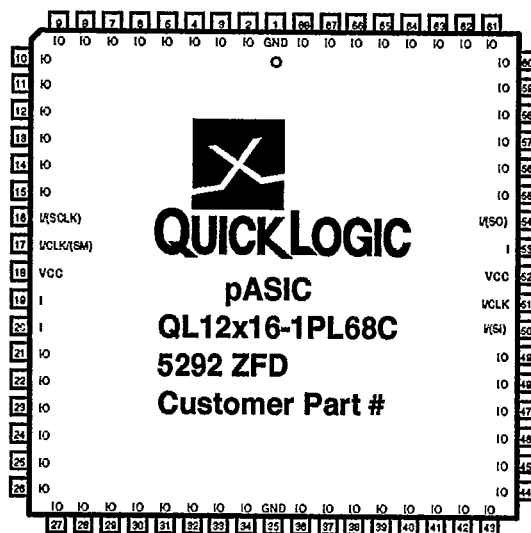
Low-impedance, metal-to-metal, ViaLink interconnect technology provides nonvolatile custom logic capable of operating at counter speeds above 100 MHz. Combined with input delays of 2 ns and output delays under 4 ns, this permits high-density programmable devices to be used with today's fastest CISC and RISC microprocessors.

Designs are entered into the QL12x16 using a pASIC Toolkit combining third-party general-purpose design entry and simulation tools with device-specific place and route and programming software. Ample on-chip routing channels are provided to allow fast, fully automatic place and route of high gate utilization designs.

## FEATURES

- ✕ 68 Bidirectional Input/Output pins
- ✕ 6 Dedicated Input/High-Drive pins
- ✕ 2 Clock/Dedicated input pins with fanout-independent, low-skew clock nets
- ✕ Input + logic cell + output delays under 9 ns
- ✕ Chip-to-chip operating frequencies up to 85 MHz
- ✕ Internal state machine frequencies up to 100 MHz
- ✕ Clock skew <1 ns
- ✕ Input hysteresis provides high noise immunity
- ✕ Built-in scan path permits 100% factory testing of logic and I/O cells and functional testing with Automatic Test Vector Generation (ATVG) software after programming
- ✕ Ample routing tracks permit fully-automatic place and route of designs using up to 100% of internal logic cells
- ✕ 84-pin PLCC compatible with ACT1020 power supply and ground pinouts
- ✕ 68-pin PLCC compatible with QL8x12 footprint for easy upgrade of designs.
- ✕ 1 $\mu$  CMOS gate array process with ViaLink programming technology

## QL12x16



Pinout  
Diagram  
68-pin PLCC

2



Pinout  
Diagram  
84-pin PLCC

Pins identified I/SCLK, SM, SO and SI are used during scan path testing operation.

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage ..... -0.5 to 7.0V  
 Input Voltage ..... -0.5 to VCC +0.5V  
 ESD Pad Protection .....  $\pm 2000V$   
 DC Input Current .....  $\pm 20\text{ mA}$   
 Latch-up Immunity .....  $\pm 100\text{ mA}$

**Storage Temperature**Ceramic .....  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ Plastic .....  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ Lead Temperature .....  $300^{\circ}\text{C}$ **OPERATING RANGE**

| Symbol | Parameter           | Military       |      | Industrial |     | Commercial |      | Unit               |
|--------|---------------------|----------------|------|------------|-----|------------|------|--------------------|
|        |                     | Min            | Max  | Min        | Max | Min        | Max  |                    |
| VCC    | Supply Voltage      | 4.5            | 5.5  | 4.5        | 5.5 | 4.75       | 5.25 | V                  |
| TA     | Ambient Temperature | -55            |      | -40        | 85  | 0          | 70   | $^{\circ}\text{C}$ |
| TC     | Case Temperature    |                | 125  |            |     |            |      | $^{\circ}\text{C}$ |
| K      | Delay Factor        | -0 Speed Grade | 0.39 | 2.12       | 0.4 | 1.94       | 0.46 | 1.80               |
|        |                     | -1 Speed Grade | 0.39 | 1.56       | 0.4 | 1.43       | 0.46 | 1.33               |
|        |                     | -2 Speed Grade |      |            |     |            | 0.46 | 1.25               |

**DC CHARACTERISTICS over operating range**

| Symbol | Parameter                      | Conditions              | Min     | Max | Unit          |
|--------|--------------------------------|-------------------------|---------|-----|---------------|
| VIH    | Input HIGH Voltage             |                         | 2.0     |     | V             |
| VIL    | Input LOW Voltage              |                         |         | 0.8 | V             |
| VOH    | Output HIGH Voltage            | IOH = -4 mA             | 3.7     |     | V             |
|        |                                | IOH = -8 mA             | 2.4     |     | V             |
|        |                                | IOH = -10 $\mu\text{A}$ | VCC-0.1 |     | V             |
| VOL    | Output LOW Voltage             | IOL = 8 mA              |         | 0.4 | V             |
|        |                                | IOL = 10 $\mu\text{A}$  |         | 0.1 | V             |
| II     | Input Leakage Current          | VI = VCC or GND         | -10     | 10  | $\mu\text{A}$ |
| IOZ    | 3-State Output Leakage Current | VI = VCC or GND         | -10     | 10  | $\mu\text{A}$ |
| CI     | Input Capacitance [1]          |                         |         | 10  | pF            |
| IOS    | Output Short Circuit Current   | VO = GND                | -10     | -80 | mA            |
|        |                                | VO = VCC                | 30      | 140 | mA            |
| ICC    | Supply Current [2]             | VI, VIO = VCC or GND    |         | 10  | mA            |

**Notes:**

- [1] CI = 20 pF Max on Pin 63
- [2] For AC conditions use the formula described in Section 5 — Power vs Operating Frequency.
- [3] Clock buffer fanout refers to the maximum number of flip flops per half column. The number of half columns used does not affect clock buffer delay.
- [4] Worst case Propagation Delay times over process variation at VCC = 5.0V and TA =  $25^{\circ}\text{C}$ . Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range. All inputs are TTL with 3 ns linear transition time between 0 and 3 volts.



# AC CHARACTERISTICS at VCC = 5V, TA = 25°C (K = 1.00)

## Logic Cell

| Symbol | Parameter               | Propagation Delays (ns) [4]<br>Fanout |     |     |     |     |
|--------|-------------------------|---------------------------------------|-----|-----|-----|-----|
|        |                         | 1                                     | 2   | 3   | 4   | 8   |
| tPD    | Combinatorial Delay [5] | 3.4                                   | 3.8 | 4.2 | 4.8 | 8.1 |
| tSU    | Setup Time [5]          | 3.7                                   | 3.7 | 3.7 | 3.7 | 3.7 |
| tH     | Hold Time               | 0.0                                   | 0.0 | 0.0 | 0.0 | 0.0 |
| tCLK   | Clock to Q Delay        | 3.0                                   | 3.3 | 3.8 | 4.3 | 4.9 |
| tSET   | Set Delay               | 2.7                                   | 3.1 | 3.5 | 4.1 | 7.4 |
| tRESET | Reset Delay             | 2.9                                   | 3.2 | 3.6 | 4.2 | 7.5 |
| tCWHI  | Clock High Time         | 2.0                                   | 2.0 | 2.0 | 2.0 | 2.0 |
| tCWLO  | Clock Low Time          | 3.6                                   | 3.6 | 3.6 | 3.6 | 3.6 |
| tSW    | Set Width               | 2.1                                   | 2.1 | 2.1 | 2.1 | 2.1 |
| tRW    | Reset Width             | 1.9                                   | 1.9 | 1.9 | 1.9 | 1.9 |

2

## Input Cells

| Symbol | Parameter                           | Propagation Delays (ns) [4]<br>Fanout |     |     |     |     |
|--------|-------------------------------------|---------------------------------------|-----|-----|-----|-----|
|        |                                     | 1                                     | 2   | 3   | 4   | 8   |
| tIN    | Input Delay (high drive)            | 3.7                                   | 3.8 | 4.2 | 4.6 | 6.4 |
| tINI   | Input, Inverting Delay (high drive) | 3.5                                   | 3.6 | 4.0 | 4.4 | 6.2 |
| tIO    | Input Delay (bidirectional pad)     | 2.3                                   | 2.6 | 3.2 | 4.1 | 5.5 |
| tGCK   | Clock Buffer Delay [3]              | 4.4                                   | 4.5 | 4.6 | 4.6 | 5.0 |

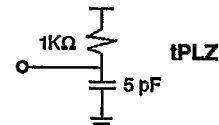
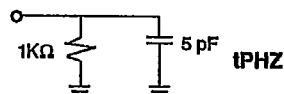
## Output Cell

| Symbol | Parameter                          | Propagation Delays (ns) [4]<br>Output Load Capacitance (pF) |     |     |     |      |
|--------|------------------------------------|-------------------------------------------------------------|-----|-----|-----|------|
|        |                                    | 30                                                          | 50  | 75  | 100 | 150  |
| tOUTLH | Output Delay Low to High           | 3.1                                                         | 3.8 | 4.6 | 5.5 | 7.2  |
| tOUTH  | Output Delay High to Low           | 3.1                                                         | 3.9 | 5.0 | 6.1 | 8.3  |
| tPZH   | Output Delay Tri-state to High     | 4.4                                                         | 5.3 | 6.5 | 7.7 | 10.1 |
| tPZL   | Output Delay Tri-state to Low      | 4.0                                                         | 4.6 | 5.4 | 6.2 | 7.7  |
| tPHZ   | Output Delay High to Tri-state [6] | 3.3                                                         |     |     |     |      |
| tPLZ   | Output Delay Low to Tri-state [6]  | 3.7                                                         |     |     |     |      |

### Notes:

[5] These limits are derived from worst case values for a representative selection of the slowest paths through the pASIC logic cell including net delays. Guaranteed delay values for specific paths should be determined from simulation results.

[6] The following loads are used for tPXZ:



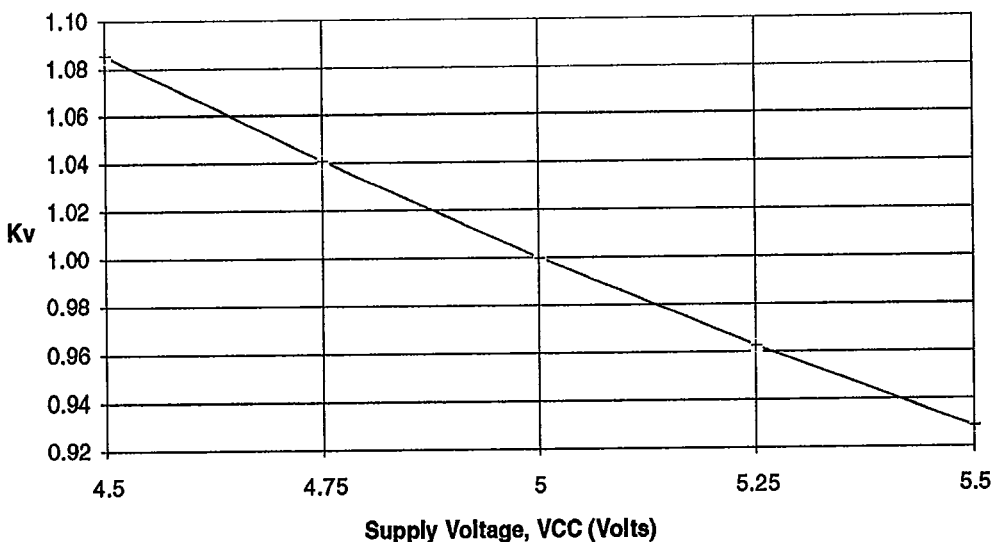
## High Drive Buffer

| Symbol | Parameter                            | # High Drives<br>Wired Together | Propagation Delays (ns) [4]<br>Fanout |      |     |      |      |
|--------|--------------------------------------|---------------------------------|---------------------------------------|------|-----|------|------|
|        |                                      |                                 | 12                                    | 24   | 48  | 72   | 96   |
| tIN    | High Drive Input Delay               | 1                               | 7.9                                   | 11.2 |     |      |      |
|        |                                      | 2                               |                                       | 8.0  | 9.7 |      |      |
|        |                                      | 3                               |                                       |      | 8.6 | 10.4 | 11.8 |
|        |                                      | 4                               |                                       |      |     | 9.4  | 10.8 |
| tINI   | High Drive Input,<br>Inverting Delay | 1                               | 7.5                                   | 10.8 |     |      |      |
|        |                                      | 2                               |                                       | 7.5  | 9.3 |      |      |
|        |                                      | 3                               |                                       |      | 8.2 | 10.0 | 11.8 |
|        |                                      | 4                               |                                       |      |     | 9.0  | 10.8 |

## AC Performance

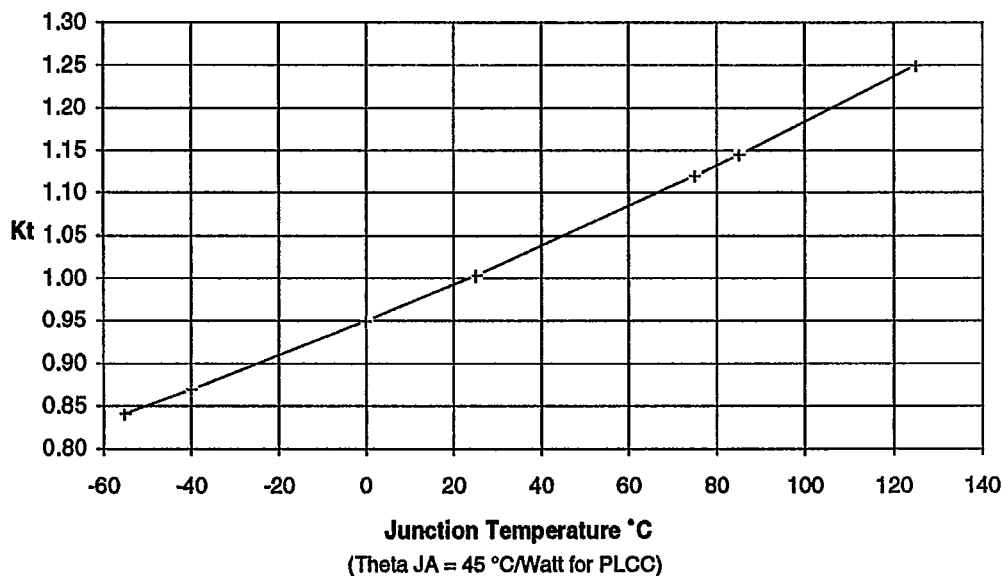
Propagation delays depend on routing, fanout, load capacitance, supply voltage, junction temperature, and process variation. The AC Characteristics are a design guide to provide initial timing estimates at nominal conditions. Worst case estimates are obtained when nominal propagation delays are multiplied by the appropriate Delay Factor, K, as specified in the Operating Range. The effects of voltage and temperature variation are illustrated in the graphs below. The SpDE Toolkit incorporates data sheet AC Characteristics into the QDIF database for pre-place-and-route simulations. The SpDE Delay Modeler extracts specific timing parameters for precise simulation results following place and route.

**Kv, Voltage Factor versus Vcc, Supply Voltage**

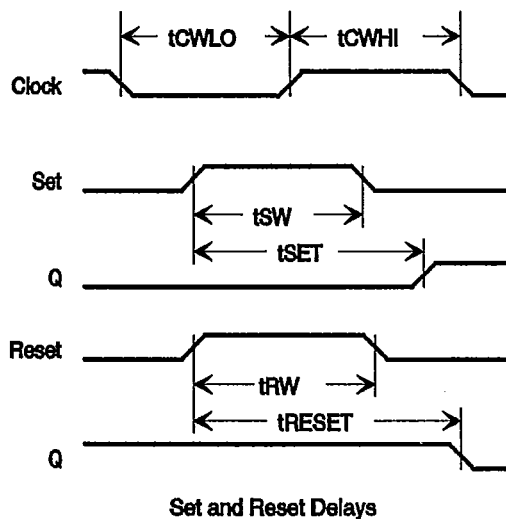
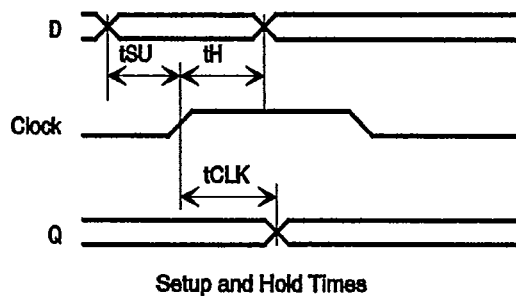
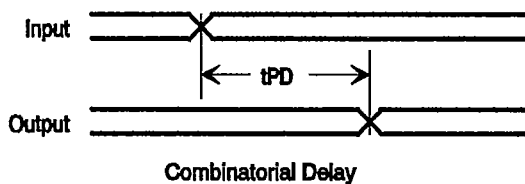




Kt, Temperature Factor versus Temperature

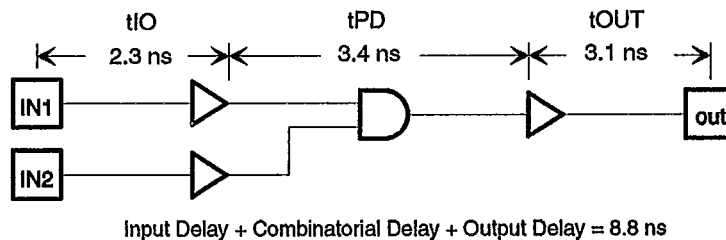


## Timing Waveforms

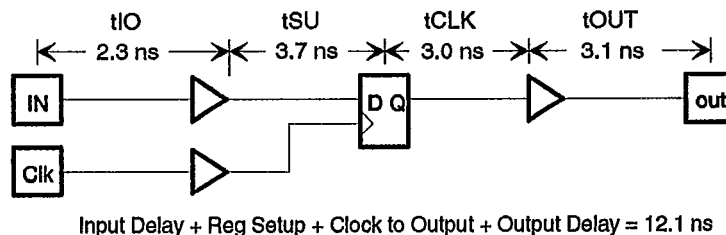


### Combinatorial Delay Example

*Nominal  
I/O Delays  
Load = 30 pF*



### Sequential Delay Example



### ORDERING INFORMATION

